Vishay General Semiconductor

Surface Mount Glass Passivated Ultrafast Rectifier





DO-214BA (GF1)

FEATURES

- Cavity-free glass-passivated junction
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low switching losses, high efficiency
- High forward surge capability
- Meets environmental standard MIL-S-19500
- Meets MSL level 1, per J-STD-020, LF maximum peak of 250 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214BA, molded epoxy over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \degree C$ unless otherwise noted)							
PARAMETER	SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT	
Device marking code		EA	EB	EC	ED		
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	V	
Maximum RMS voltage	V _{RMS}	35	70	105	140	V	
Maximum DC blocking voltage	V _{DC}	50	100	150	200	V	
Maximum average forward rectified current at T_L = 125 °C	I _{F(AV)}		А				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}		А				
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175				°C	

PRIMARY CHARACTERISTICS						
I _{F(AV)}	1.0 A					
V _{RRM}	50 V to 200 V					
I _{FSM}	30 A					
t _{rr}	50 ns					
V _F	1.0 V					
T _J max.	175 °C					



ROHS COMPLIANT





EGF1A thru EGF1D

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \degree C$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT
Maximum instantaneous forward voltage $^{(1)}$	1.0 A		V _F	1.0				V
Maximum DC reverse current at rated DC blocking voltage ⁽¹⁾		T _A = 25 °C T _A = 125 °C	I _R	5.0 50		μA		
Typical reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A		t _{rr}	50			ns	
Typical junction capacitance	4.0 V, 1 MHz		CJ	15			pF	

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	EGF1A	EGF1B	EGF1C	EGF1D	UNIT	
Typical thermal resistance ⁽¹⁾	$R_{ extsf{ heta}JA}\ R_{ extsf{ heta}JL}$	85 30		°C/W			

Note:

(1) Thermal resistance from junction to ambient and from junction to lead, P.C.B. mounted on 0.2 x 0.2" (5.0 x 5.0 mm) copper pad areas

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
EGF1D-E3/67A	0.104	67A	1500	7" diameter plastic tape and reel			
EGF1D-E3/5CA	0.104	5CA	6500	13" diameter plastic tape and reel			
EGF1DHE3/67A (1)	0.104	67A	1500	7" diameter plastic tape and reel			
EGF1DHE3/5CA ⁽¹⁾	0.104	5CA	6500	13" diameter plastic tape and reel			

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise specified)

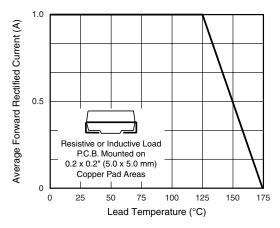


Figure 1. Maximum Forward Current Derating Curve

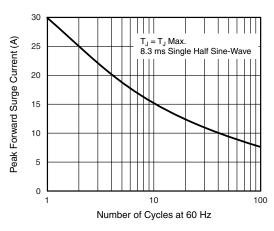


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



EGF1A thru EGF1D

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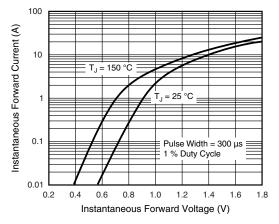


Figure 3. Typical Instantaneous Forward Characteristics

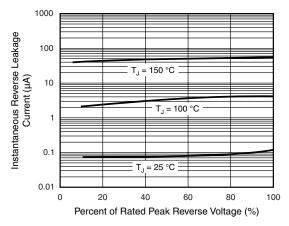


Figure 4. Typical Reverse Leakage Characteristics

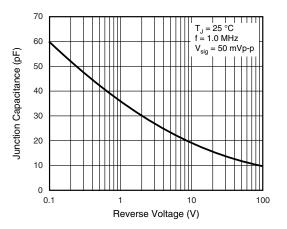


Figure 5. Typical Junction Capacitance

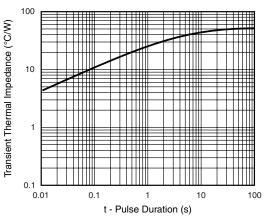
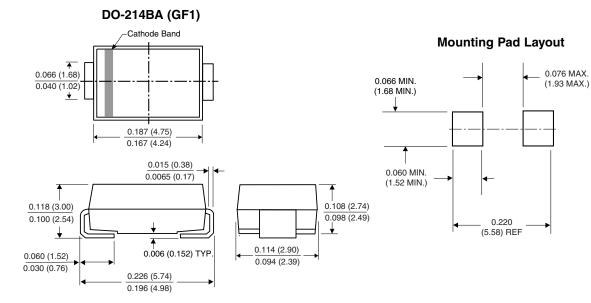


Figure 6. Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



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